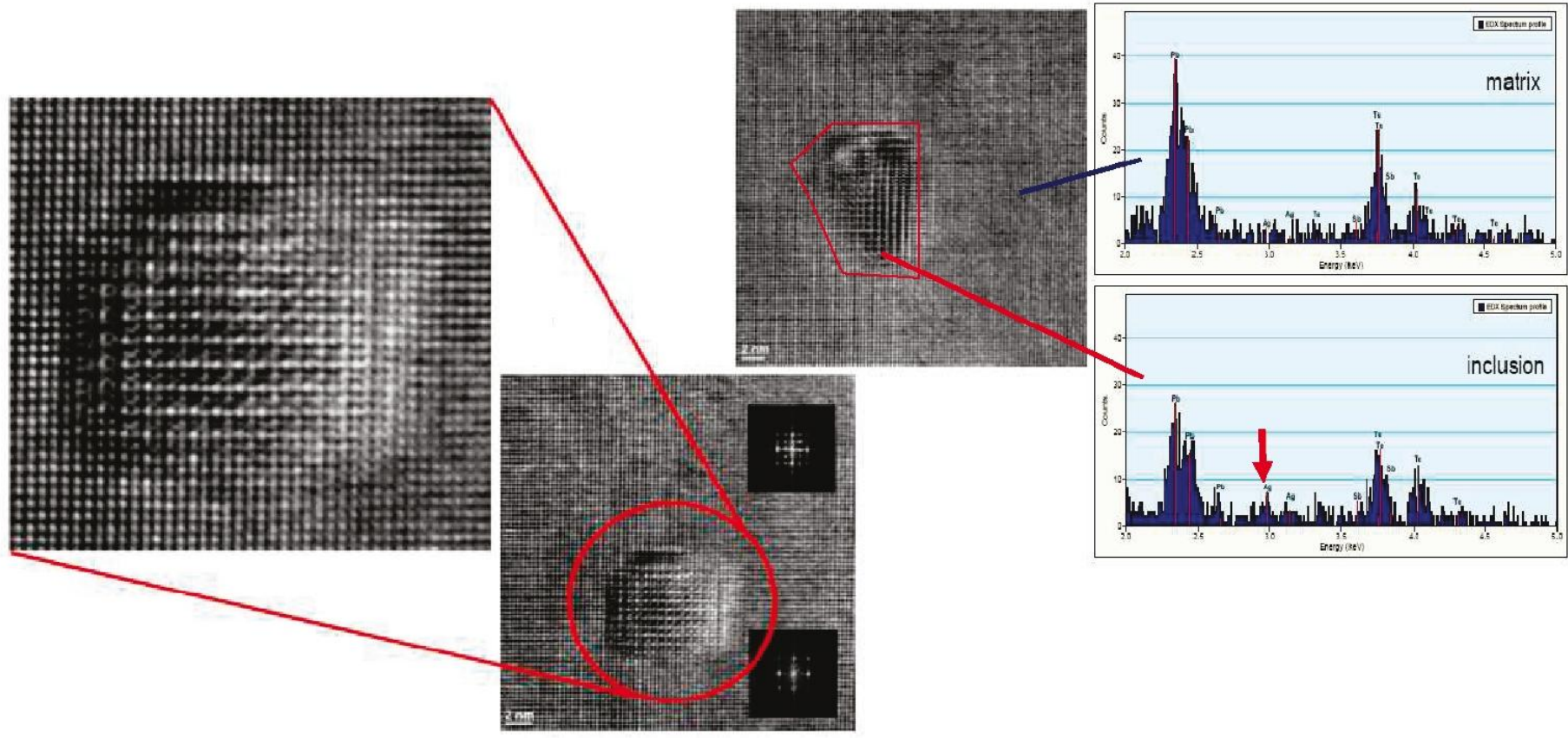


Nanostructured Thermoelectrics



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MATRL 286G
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Bruce A. Cook, Matthew J. Kramer, Joel L. Harringa, Mi-Kyung Han, Duck Young Chung, Mercuri G. Kanatzidis, Analysis of Nanostructuring in $Ag_{1-x}Pb_mSbTe_{2+m}$ High Figure-of-Merit Thermoelectric Materials, *Advanced Functional Materials*, **2009**, 19, 1254-1259.

Motivation

Heat Recovery

~90% of world's energy produced by heat energy (fossil fuels)
30-40% efficiency, lose 15 TW energy as waste heat

Refrigeration

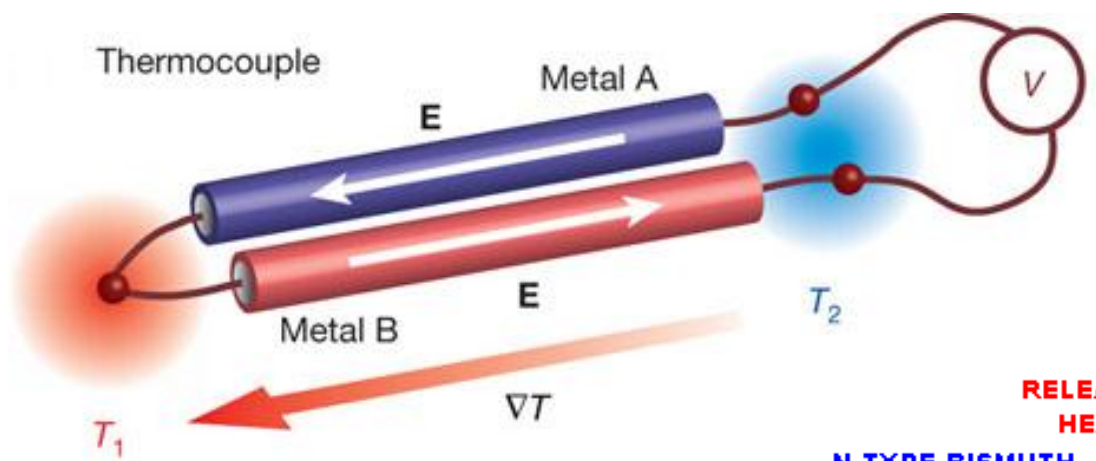
Reduce CFC and HCFC release to atmosphere

Solid State Heating/Cooling

no moving parts
niche applications (car seat heater,
cooling/heating in space)

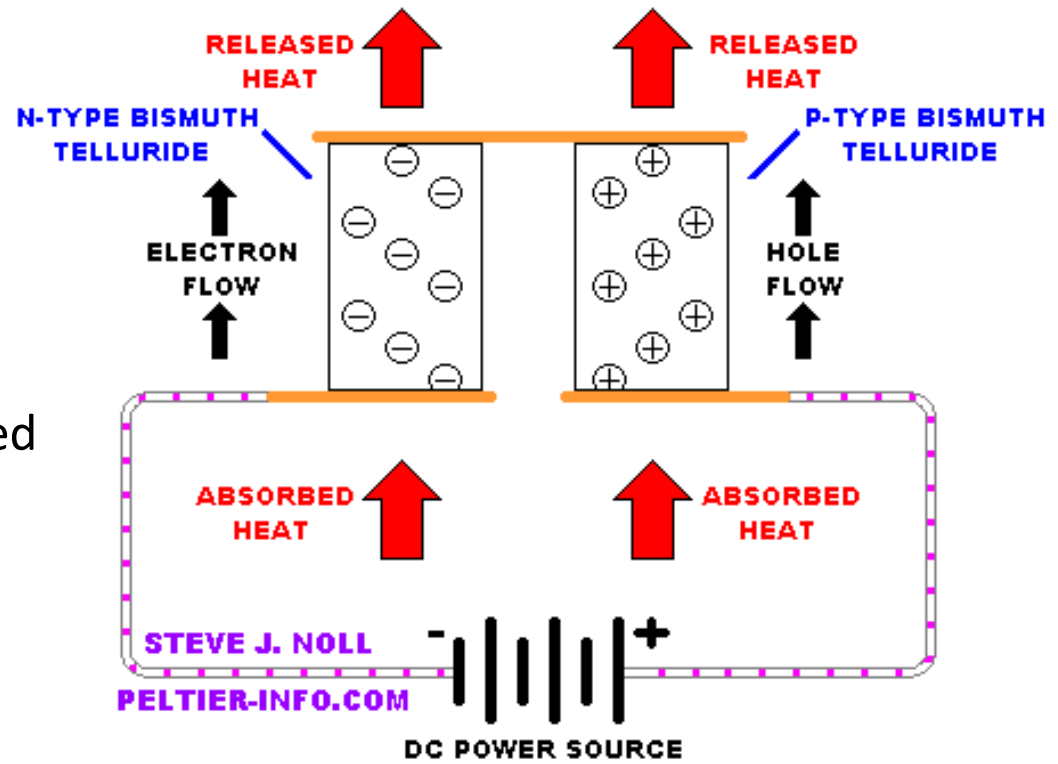


Electricity \longleftrightarrow ΔT



Seebeck effect
Voltage caused by
temperature gradient

Peltier effect
Temperature gradient caused
by application of voltage



Thermoelectric Figure of Merit

$$S = \frac{\Delta T}{\Delta V}$$

$$ZT = \frac{\sigma S^2 T}{\kappa}$$

$$\kappa = \kappa_{el} + \kappa_{latt}$$

$$\kappa_{latt} = \frac{1}{3} C_v l v_s$$

S = Seebeck coefficient	[$\mu\text{V}/\text{K}$]
σ = electrical conductivity	[S/cm]
κ = thermal conductivity	[W/m \cdot K]
C_v = specific heat	[W/kg \cdot K]
l = mean free phonon path	[nm]
v_s = average velocity of sound	[m/s]

$$\sigma S^2 = \text{power factor} \quad [\mu\text{W}/\text{K}^2\text{cm}]$$

Maximum attainable Z

$$Z_{\max} \propto \gamma \frac{T^{3/2} \tau_z \sqrt{\frac{m_x m_y}{m_z}}}{\kappa_{\text{latt}}} e^{(r+1/2)}$$

γ = degeneracy of band extrema

m_i = effective mass of carriers in i-th direction

τ_z = relaxation time of the carriers moving
along the transport direction (usually z)

r = scattering parameter

κ_{latt} = lattice thermal conductivity

Strategies for improving ZT by lowering κ_{latt}

Alloys

Bi_2Te_3 system, $\text{Bi}_{2-x}\text{Sb}_x\text{Te}_3$ $\text{BiTe}_{3-x}\text{Se}_x$

“Alloy limit”-minimum κ_{latt} at some composition

Can deteriorate carrier mobility

Phonon-glass-electron crystal (PGEC)

Large rattling atoms in cages or tunnels

Not proven, other factors affect κ

Nanostructuring

Self-formed inhomogenieties driven by phase segregation

Nanocomposites (spark plasma sintering, hot pressing, etc.)

Liquid encapsulation (PbTe-PbS)

AgPb_mSbTe_{2+m} (LAST-*m*)

PbTe

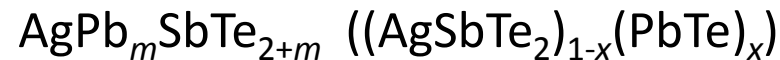
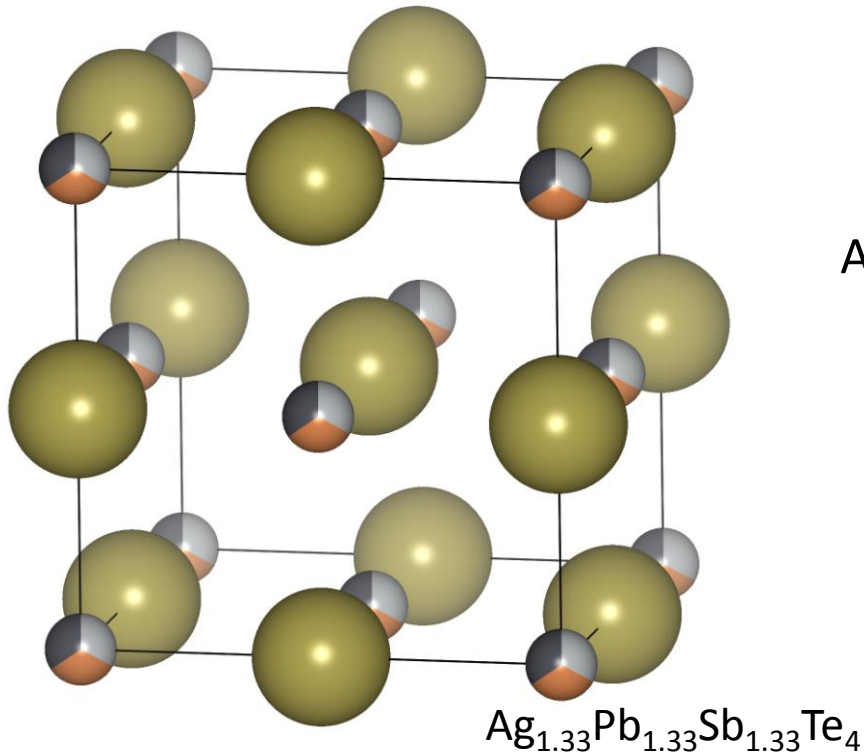
600-800 K range

NaCl structure (SG Fm-3m #225)

0.32 eV band gap, can be doped p- or n-type

Max ZT 0.8-1.0 at ~650 K

$\kappa_{\text{latt}} \sim 2.2 \text{ W}/(\text{m} \cdot \text{K})$ at 293 K, falls off at higher temp as $1/T$



$m < 10$ results in phase segregation

$m > 10$ appear to follow Vegard's law

Not solid solution; nanostructuring occurs

AgPb_mSbTe_{2+m} (LAST-*m*) Synthesis

$m < 10$

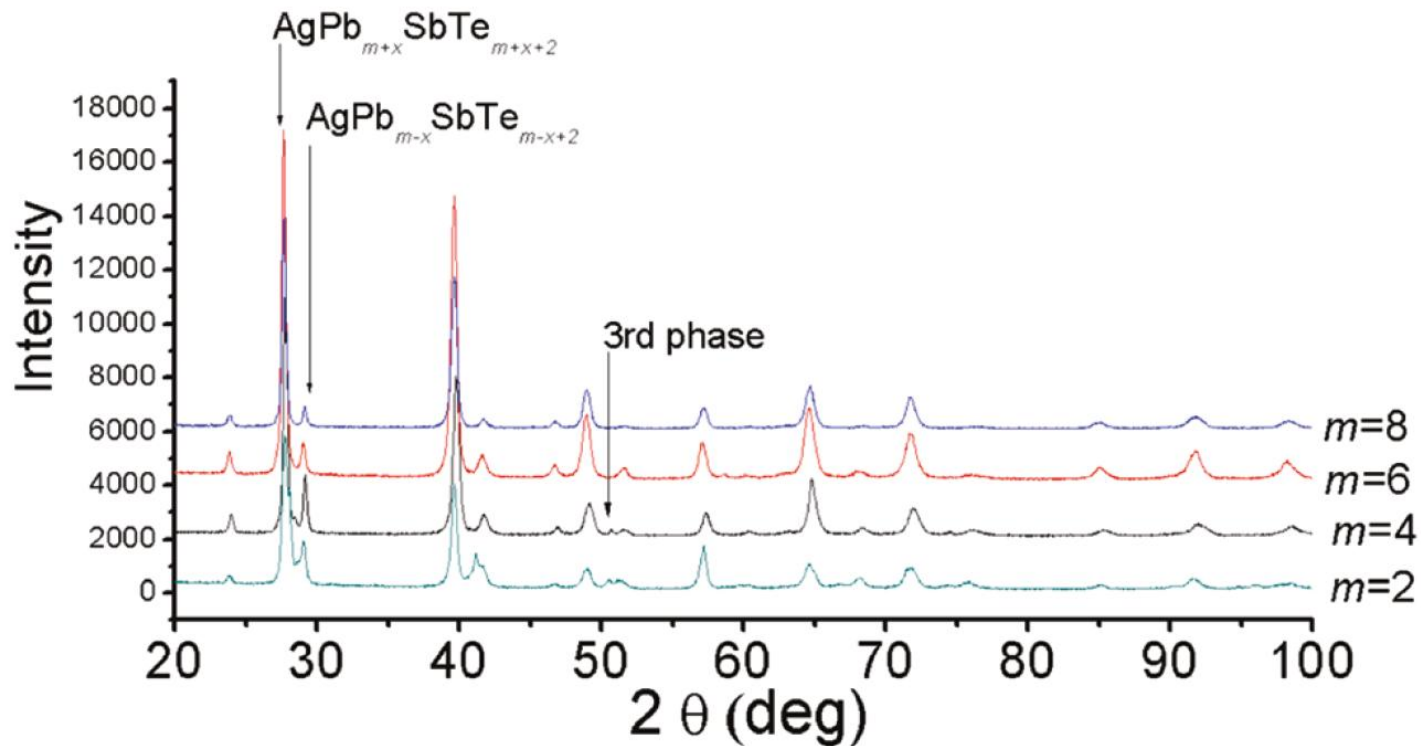
AgSbTe₂ and PbTe Melted (>1200 °C)

Quench or slowly cool below 500 °C, single phase observed

Anneal at ~400 °C (if quenched)

Microscopic phase separation results

$\kappa_{\text{latt}} \sim 1 \text{ W}/(\text{m} \cdot \text{K})$

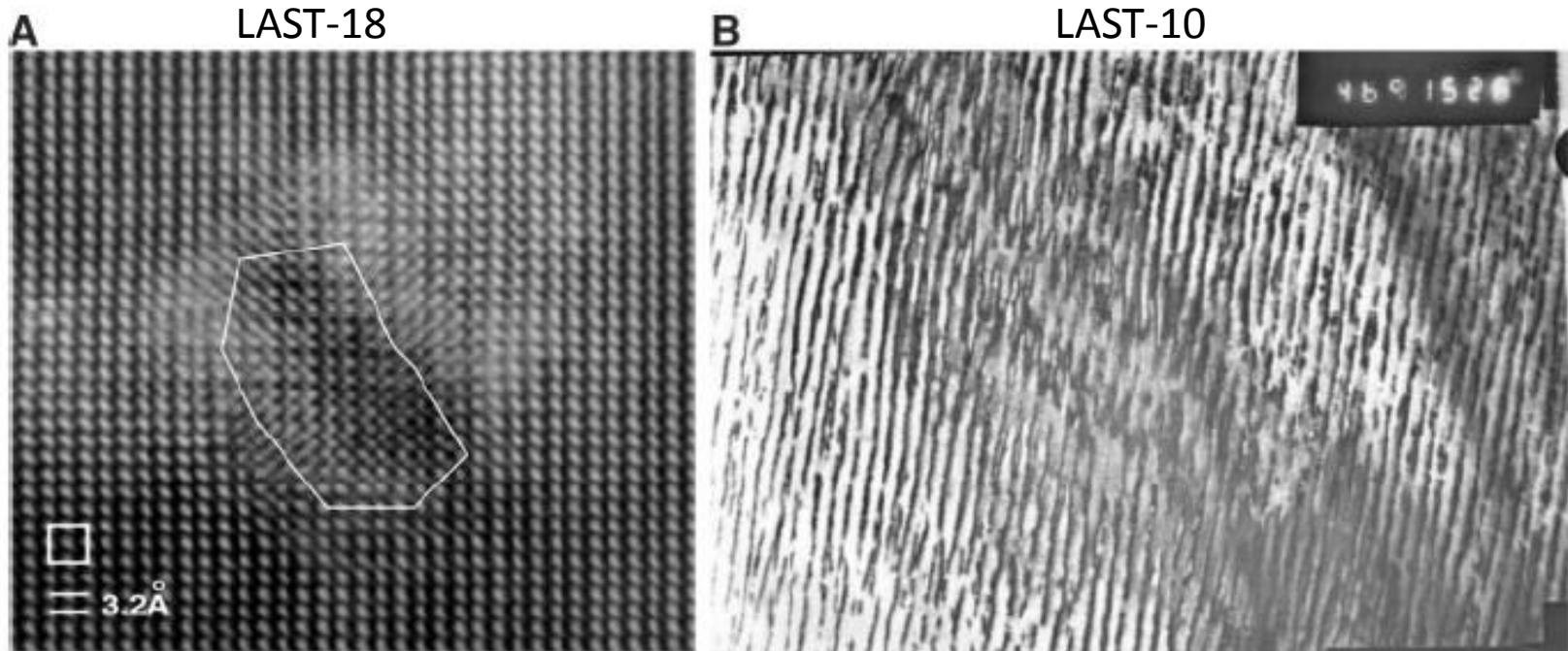


$\text{AgPb}_m\text{SbTe}_{2+m}$ (LAST- m) Synthesis

$m > 10$

AgSbTe_2 and PbTe Melted (>1200 °C)

Slowly cool below 500 °C, single phase observed



Nanoscale phase segregation from nucleation and growth (3-20 nm)

Nanoscale inclusions disrupt medium/long range phonons (change l)

Anisotropy (10-20 nm spacing) from periodic conc. changes effective carrier masses

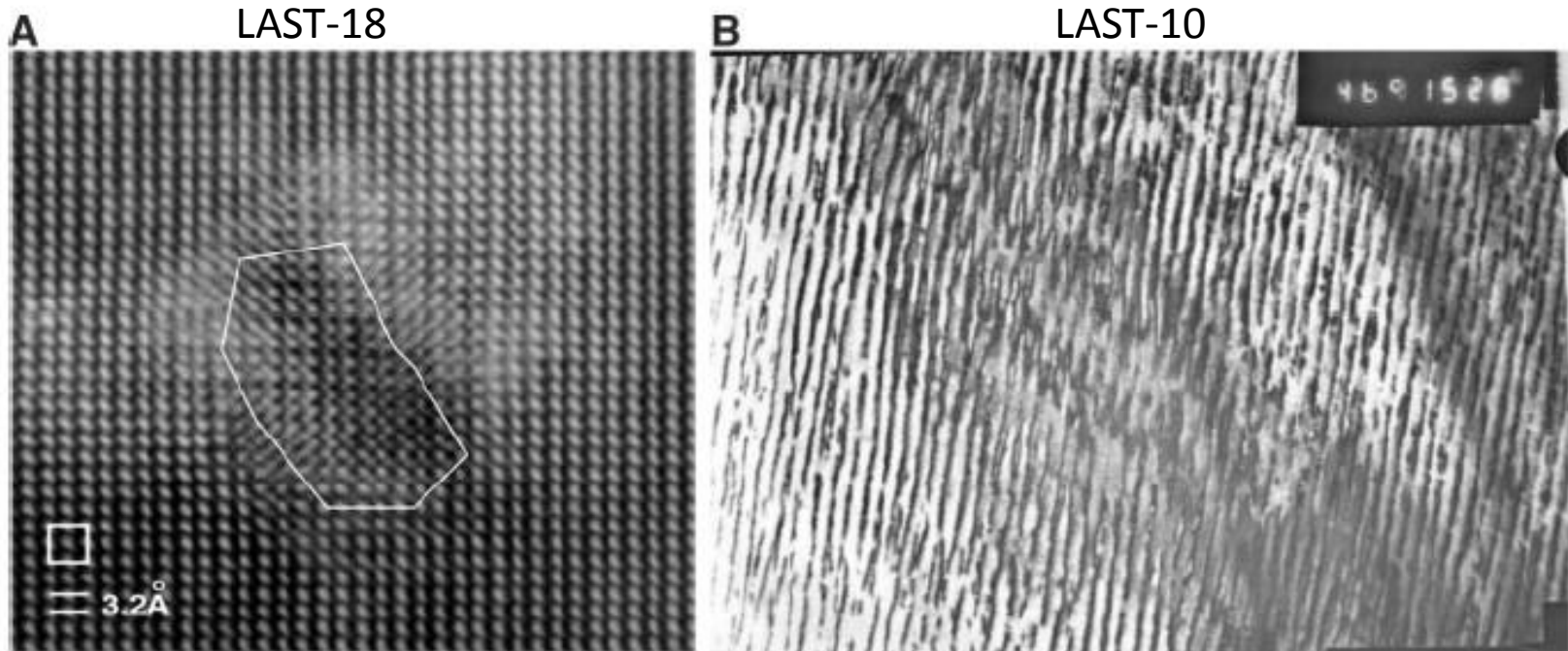
LAST-18 -- $\kappa_{\text{latt}} \sim 1\text{W}/(\text{m}\cdot\text{K})$, $\sigma \sim 200$ S/cm, $ZT \sim 2.2$, at 800 K, $\sigma \sim 1800$ S/cm at 300K

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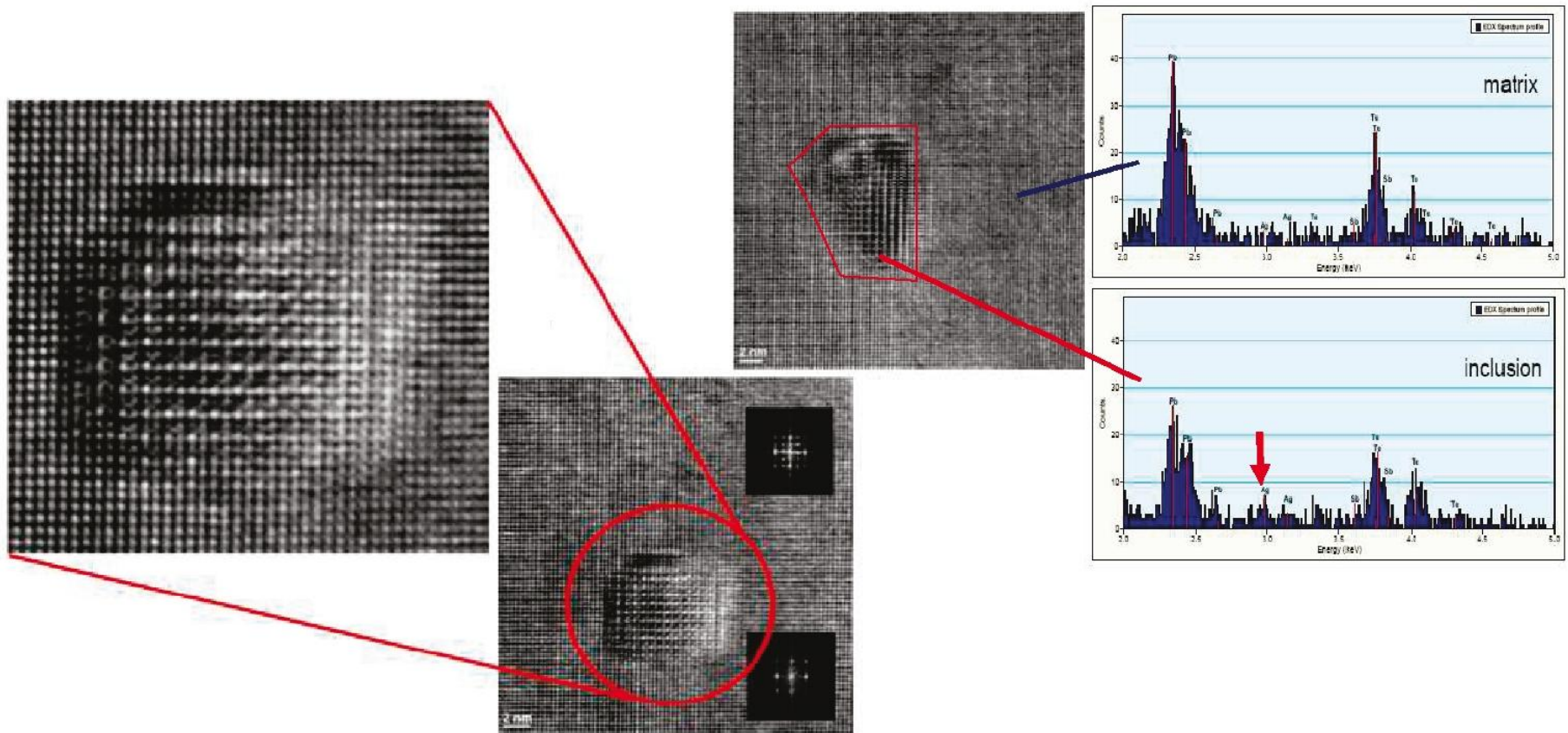
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AgPb_mSbTe_{2+m} (LAST-*m*) nanostructuring

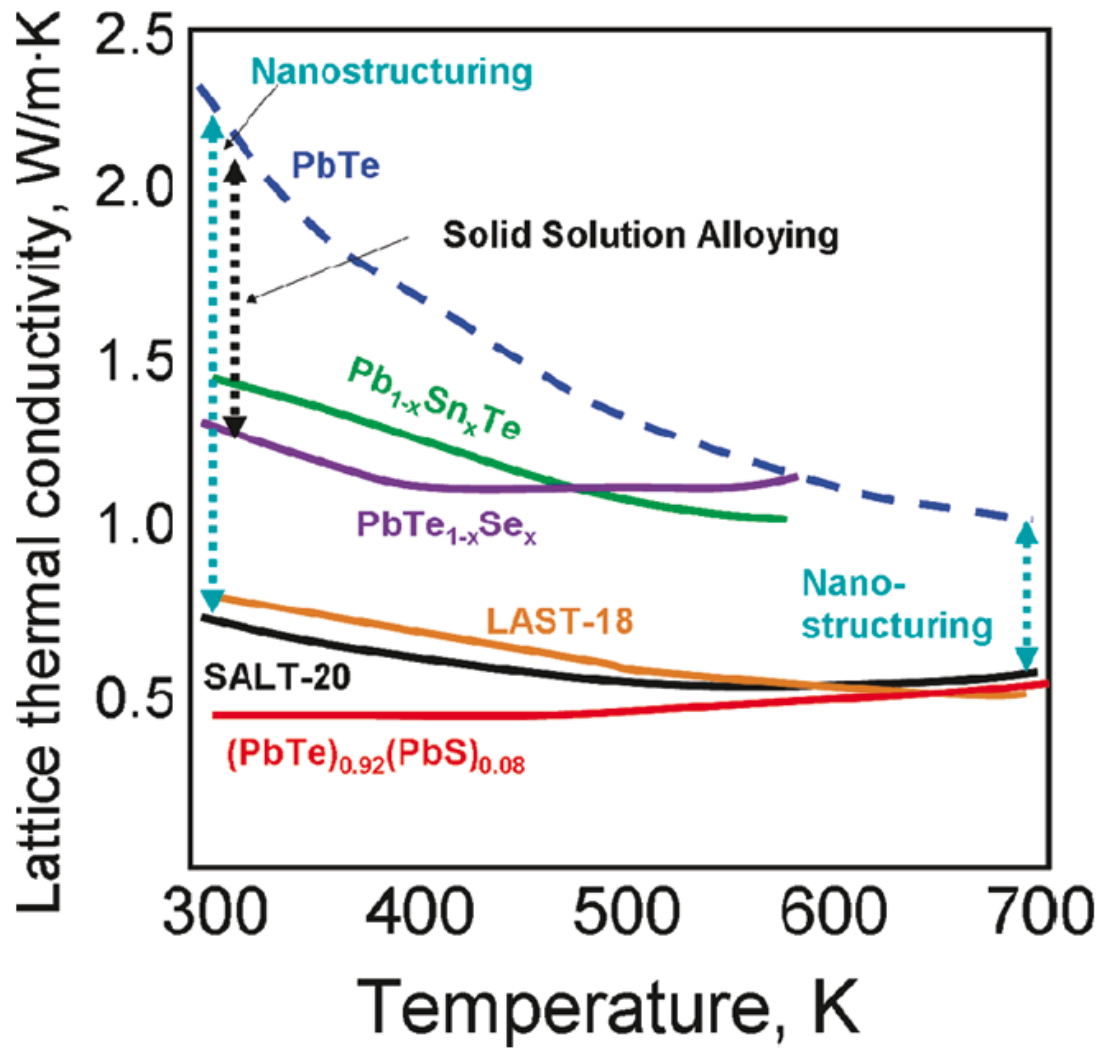
TEM of nanoscale phase segregation (~20 nm diameter particle)

Surrounding area is Ag/Sb poor, cell parameter ~PbTe (6.44 Å)

EDS shows the nanoscale inclusion is Ag-rich

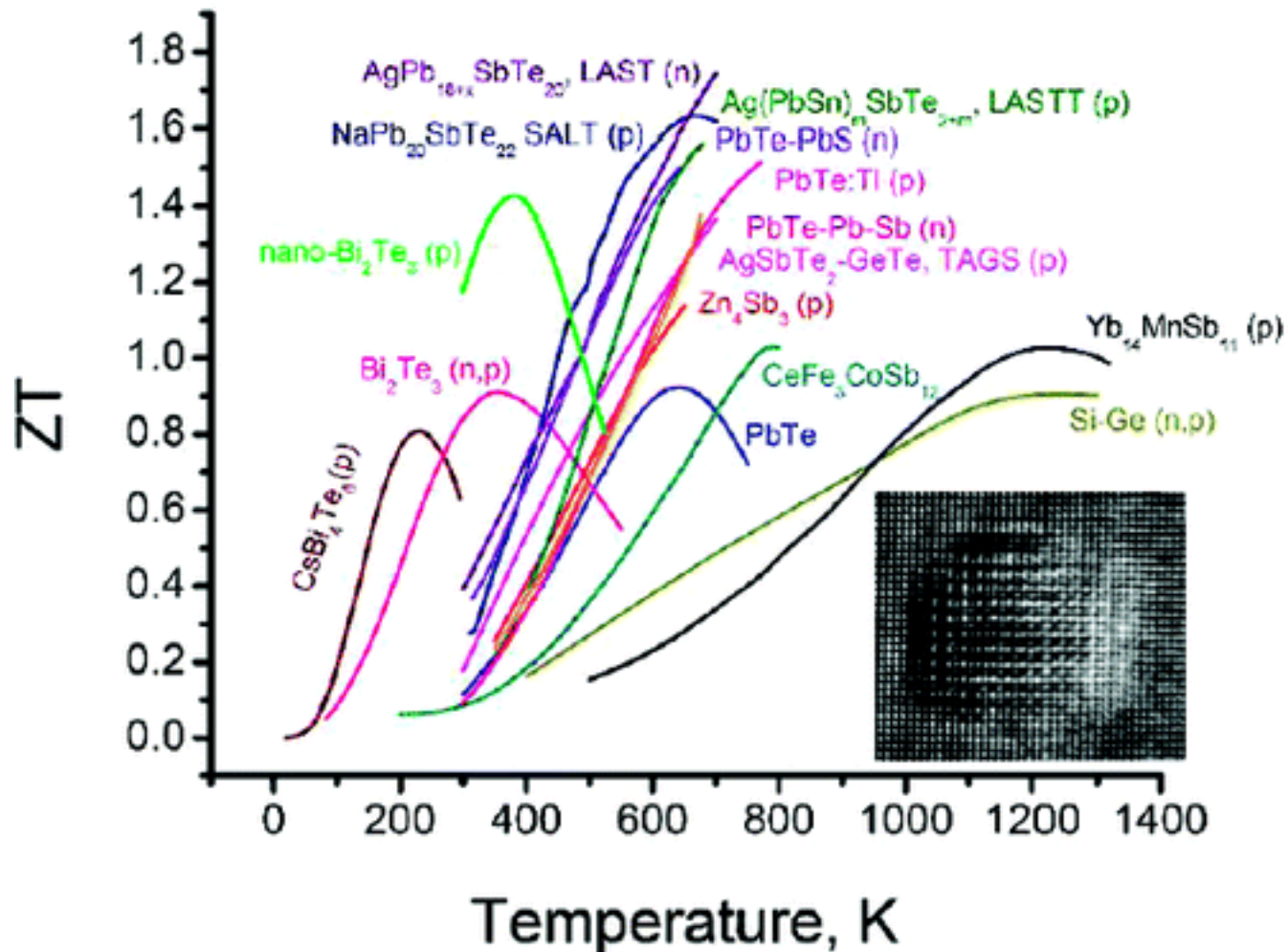


Nanostructuring enables new lows of κ_{latt}



ZT doubled by nanostructuring

Efficiencies up from 5-6% to 11-15%



“It is evident that the field of thermoelectrics now needs new bold theoretical guidance on how the power factor can be enhanced by 2--4-fold in the existing leading materials, especially enhancements that derive from the thermopower. Theorists in the field are urged to take risks.”